

D1N5806

SINTERED GLASS JUNCTION AVALANCHE RECTIFIER

VOLTAGE: 160V

CURRENT: 1.0A



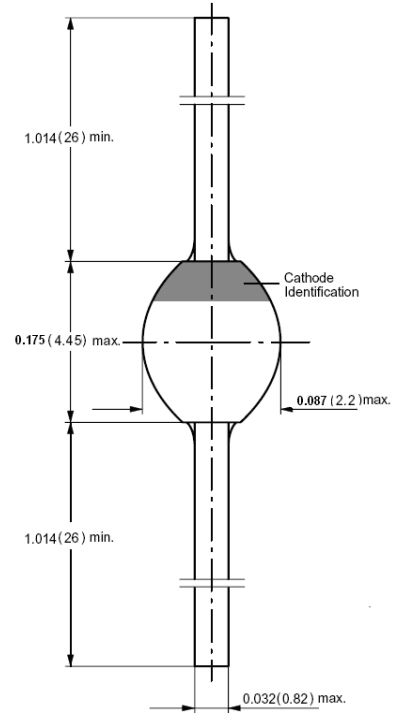
FEATURE

Glass passivated
Hermetically sealed package
Low reverse current

MECHANICAL DATA

Case: SOD-57 sintered glass case
Terminal: Plated axial leads solderable per MIL-STD 750, method 2026
Polarity: color band denotes cathode end
Mounting position: any

SOD-57-1



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

	SYMBOL	D1N5806	units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	160	V
Maximum RMS Voltage	V_{RMS}	112	V
Maximum DC blocking Voltage	V_{DC}	160	V
Maximum Average Forward Rectified Current 3/8"lead length at $T_a=55^\circ C$	I_{FAV}	1.0	A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I_{FSM}	25	A
Maximum Forward Voltage at rated Forward Current 1.0A and 25°C	V_F	0.875	V
Maximum DC Reverse Current at $V_{DC}=160V$ and 25°C	I_R	1.0	μA
Maximum DC Reverse Current at $V_{DC}=160V$ and 150°C	I_R	200	μA
Maximum Reverse Recovery Time (Note 1)	T_{rr}	25	nS
Typical Junction Capacitance (Note 2)	C_j	25.0	pF
Typical Thermal Resistance (Note 3)	$R_{th}(j_a)$	45.0	$^\circ C/W$
Storage and Operating Junction Temperature	T_{stg}, T_j	-65 to +175	$^\circ C$

Note:

- Reverse Recovery Condition $I_f=0.5A, I_r=1.0A, I_{rr}=0.25A$
- Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
- Thermal Resistance from Junction to Ambient at 3/8"lead length, P.C. Board Mounted

RATINGS AND CHARACTERISTIC CURVES D1N5806

FIG. 1 - FORWARD CURRENT DERATING CURVE

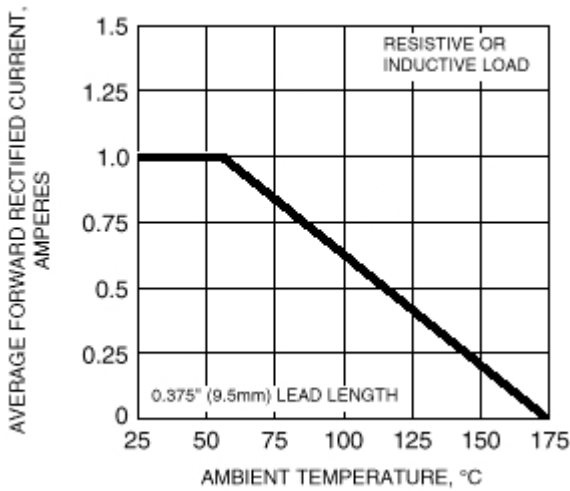


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

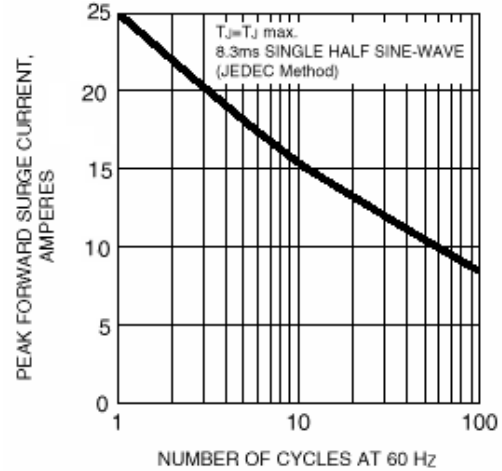


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

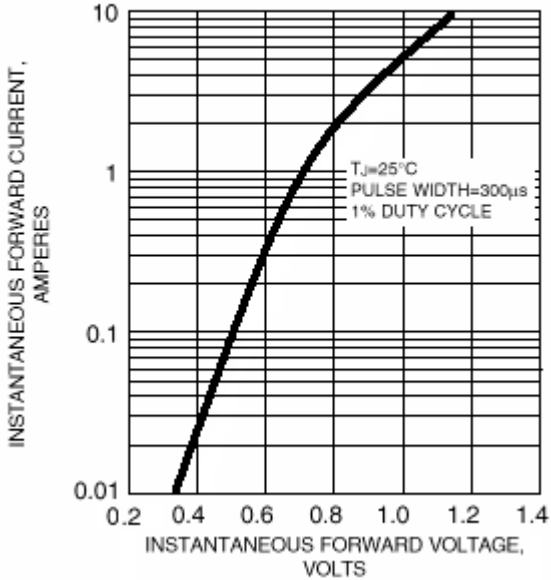


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

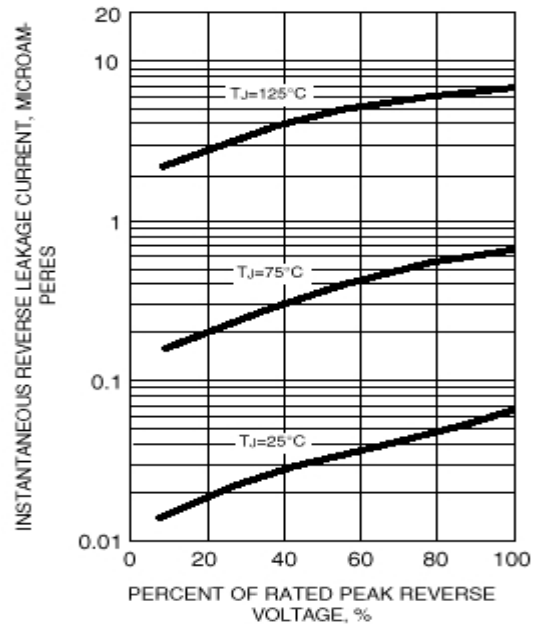


FIG. 5 - TYPICAL JUNCTION CAPACITANCE

